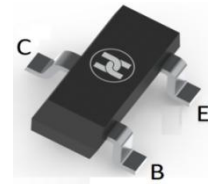
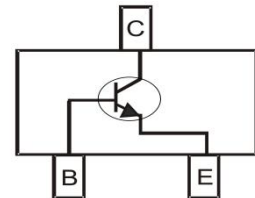


BIPOLAR TRANSISTOR (NPN)
FEATURES

- High power gain
- Low Noise
- For Low Noise Amplifier at UHF/VHF/CATV Band
- Surface Mount device


SOT-23
MECHANICAL DATA

- Case: SOT- 23
- Case Material: Molded Plastic. UL flammability
- Classification Rating: 94V-0
- Weight: 0.008 grams (approximate)


MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	20	V
Collector-Emitter Voltage	V _{CEO}	12	V
Emitter-Base Voltage	V _{EBO}	3	V
Collector Current	I _C	100	mA
Collector Power Dissipation	P _C	200	mW
Junction Temperature	T _J	150	°C
Storage Temperature	T _{STG}	-55 ~+150	°C

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Collector-base breakdown voltage	V _{(BR)CBO}	20			V	I _C =10uA, I _E =0
Collector-emitter breakdown voltage	V _{(BR)CEO}	12			V	I _C =1mA, I _B =0
Emitter-base breakdown voltage	V _{(BR)EBO}	3			V	I _E =10uA, I _C =0
Collector cut-off current	I _{CBO}			1	uA	V _{CB} =10V, I _E =0
Emitter cut-off current	I _{EBO}			1	uA	V _{EB} =1V, I _C =0
DC current gain	h _{FE}	50	120	300		V _{CE} =10V, I _C =20mA
Insertion Power Gain	S _{21e} ²		11.5		dB	V _{CE} =10V, I _C =20mA, f=1GHz
Transition frequency	f _T		7		GHz	V _{CE} =10V, I _C =20mA
Collector output capacitance	C _{ob}		0.55	1.0	pF	V _{CB} =10V, I _E =0, f=1MHz
Noise figure	NF		1	2	dB	V _{CE} =10V, I _C =7mA, f=1GHz

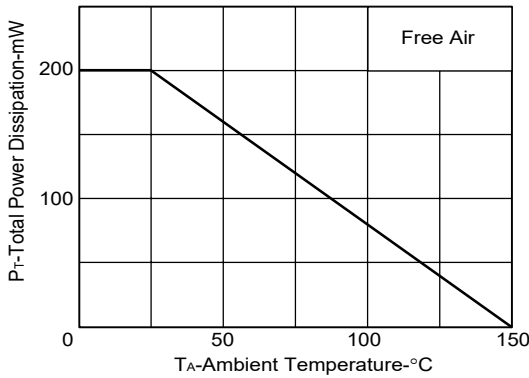
CLASSIFICATION OF h_{FE}

Rank	Q	R	S	T
Range	50-100	80-160	125-250	200-330
Marking	R23	R24	R25	R26

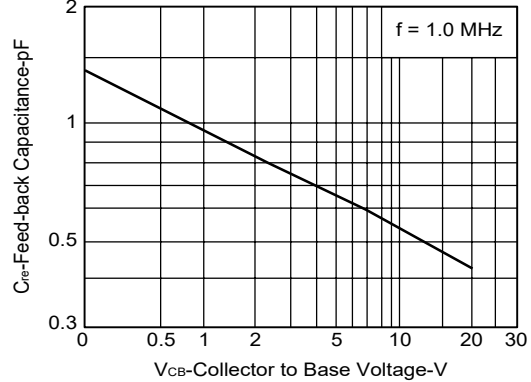
BIPOLAR TRANSISTOR (NPN)

Typical Characteristics

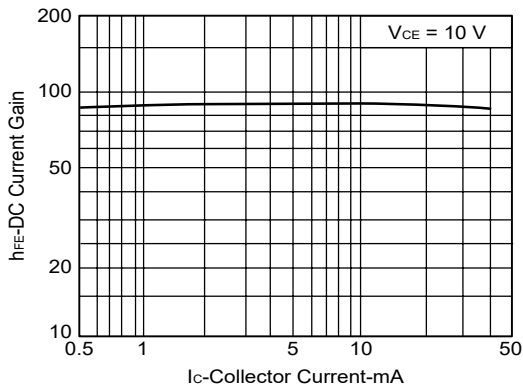
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



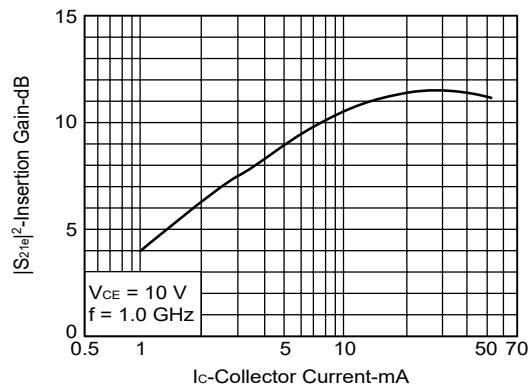
FEED-BACK CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



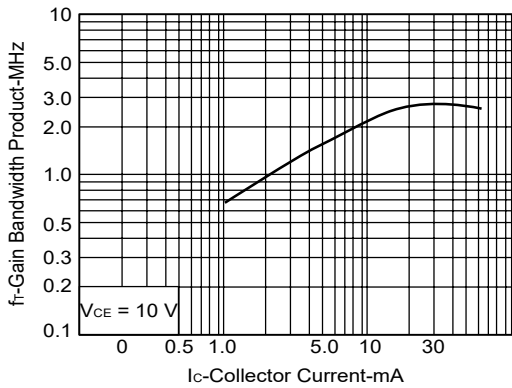
DC CURRENT GAIN vs. COLLECTOR CURRENT



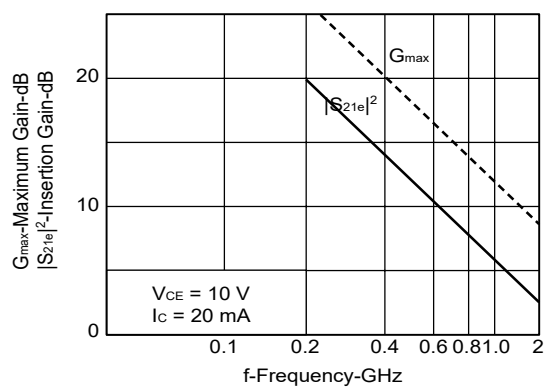
INSERTION GAIN vs. COLLECTOR CURRENT



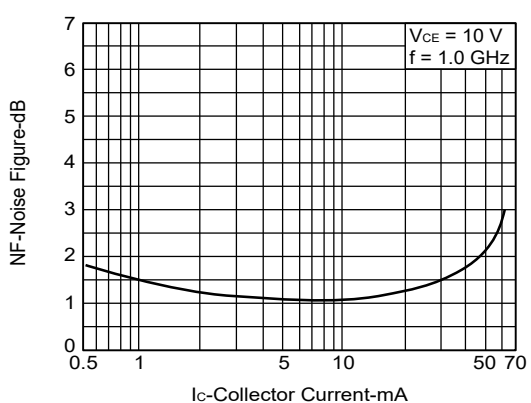
GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



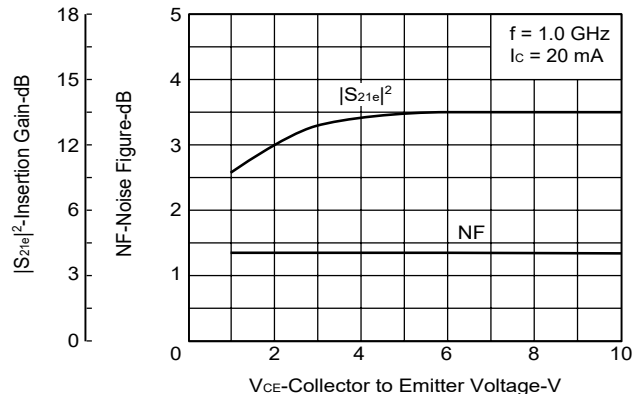
INSERTION GAIN, MAXIMUM GAIN vs. FREQUENCY



NOISE FIGURE vs. COLLECTOR CURRENT

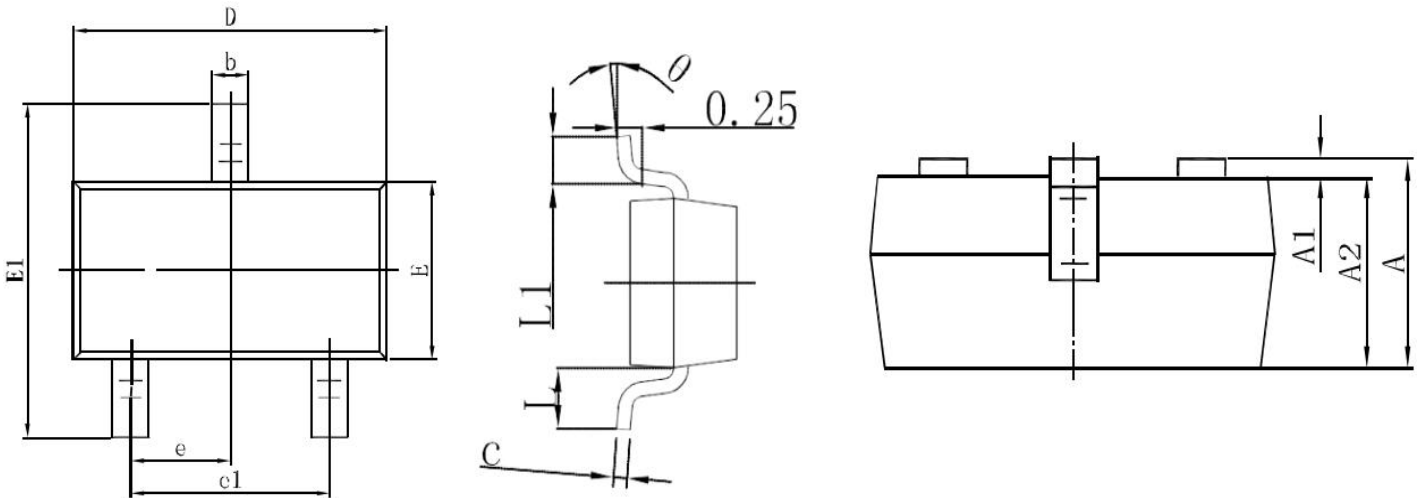


NOISE FIGURE, FORWARD INSERTION GAIN vs. COLLECTOR TO EMITTER VOLTAGE



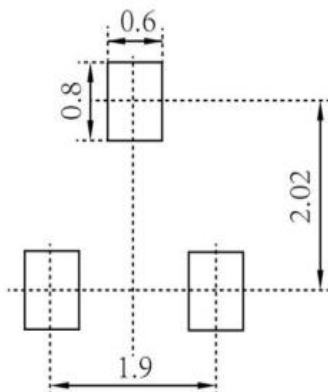
BIPOLAR TRANSISTOR (NPN)

SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.354	0.453
A1	0.000	0.100	0.000	0.039
A2	0.900	1.050	0.354	0.413
b	0.300	0.500	0.118	0.197
c	0.080	1.150	0.031	0.453
D	2.900	3.100	1.142	1.220
E	1.200	1.400	0.472	0.551
E1	2.250	2.550	0.886	1.004
e	0.95REF		0.374REF	
e1	1.800	2.000	0.709	0.787
L	0.55REF		0.215REF	
L1	0.300	0.500	0.118	0.197

SOT-23 Suggested Pad Layout



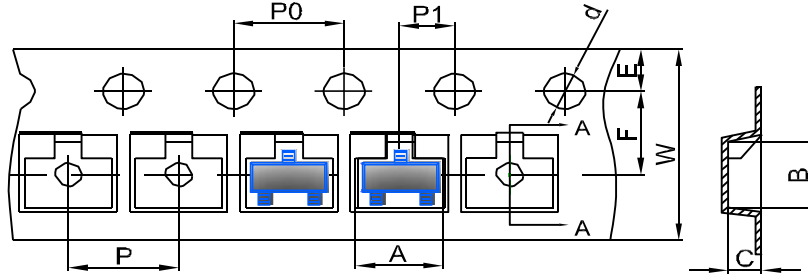
Note:

1. Controlling dimension: in millimeters
2. General tolerance: $\pm 0.05\text{mm}$
3. The pad layout is for reference purposes only

BIPOLAR TRANSISTOR (NPN)

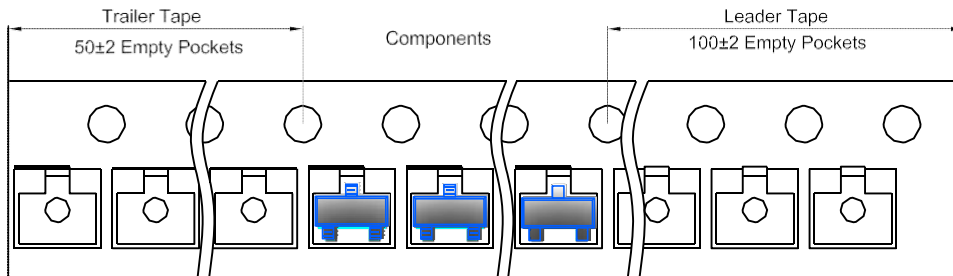
SOT-23 Tape and Reel

SOT-23 Embossed Carrier Tape

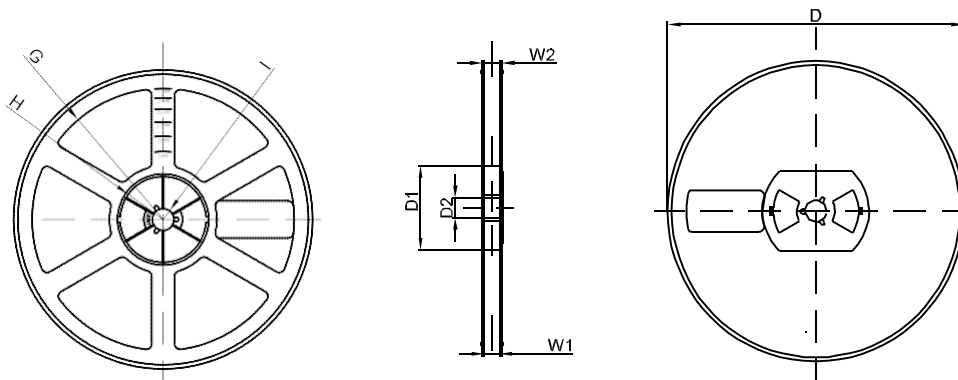


DIMENSIONS ARE IN MILLIMETER										
TYPE	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00
TOLERANCE	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1

SOT-23 Tape Leader and Trailer



SOT-23 Reel



DIMENSIONS ARE IN MILLIMETER								
REEL OPTION	D	D1	D2	G	H	I	W1	W2
7" DIA	Ø178	54.40	13.00	R78	R25.60	R6.50	9.50	12.30
TOLERANCE	±2	±1	±1	±1	±1	±1	±1	±1